

### Hynetek Semiconductor Co., Ltd.

# HUSB238

#### FEATURES

USB-IF certified • TID: 3666 Standalone USB Power Delivery (PD) sink controller Legacy charging sink Apple divider 3 detection BC1.2 SDP, CDP and DCP detection Dead battery function SOP' communication function 3V to 25V operation range 30V voltage rating on VIN and GATE pins 25V voltage rating on CC1 and CC2 pins I<sup>2</sup>C access for monitoring and advanced settings Integrated PMOS driver VBUS over-voltage protection (OVP) and undervoltage protection (UVP) Over-temperature protection (OTP) with programmable thresholds Low power consumption

### **APPLICATIONS**

PD sink devices USB-C cables Wireless charger

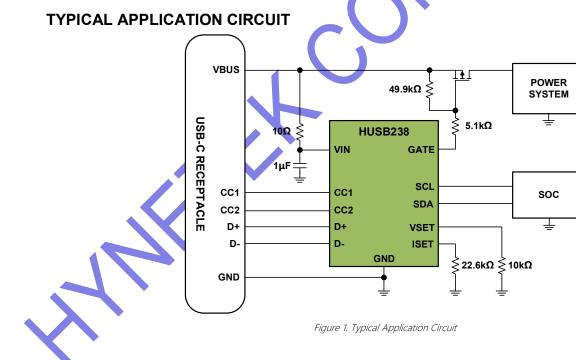
#### **GENERAL DESCRIPTION**

The HUSB238 is a highly integrated USB Power Delivery (PD) controller as sink role for up to 100W power rating.

The HUSB238 is compatible with PD3.0 and Type-C V1.4, and it can also support Apple Divider 3, BC1.2 SDP, CDP and DCP while the source is attached.

The HUSB238 can be used in electronic devices that have legacy barrel connectors or USB micro-B connectors for power such as IoT (Internet of Things) devices, wireless charger, drones, smart speakers, power tools, and other rechargeable devices.

The HUSB238 is available in 3mm x 3mm DFN-10L package.



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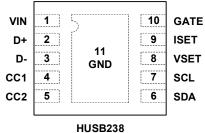
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# **REVISION HISTORY**

-	Version	Date	Descriptions
	Rev. 1.0	10/2020	Initial version

### **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**



#### DFN-10

Figure 2. Pin Configuration (Top View)

#### **Table 1. Pin Function Descriptions**

Pin No.	Pin Name	Type <sup>1</sup>	Description
1	VIN	Р	Power supply input. Connect this pin to VBUS of USB Type-C connector and bias this pir via a $1\mu$ F ceramic capacitor.
2	D+	DIO	Positive line of USB 2.0 data line for Apple Divider 3 and BC1.2.
3	D-	DIO	Negative line of USB 2.0 data line for Apple Divider 3 and BC1.2.
4	CC1	AIO	Configuration line 1 used to negotiate a voltage/current with the attached adapter.
5	CC2	AIO	Configuration line 2 used to negotiate a voltage/current with the attached adapter.
6	SDA	DIO	I <sup>2</sup> C communication data signal.
7	SCL	DIO	I <sup>2</sup> C communication clock signal.
8	VSET	AI	Connect a resistor to indicate the maximum voltage needed by the system from the attached power adapter.
9	ISET	AI	Connect a resistor to indicate the maximum current needed by the system from the attached power adapter.
10	GATE	OD	Open drain gate driver output. Connect this signal to the gate of an external PMOS through a series resistor. Leave this pin open if not used.
11	GND	Р	Ground reference. All signals are referred to this pin.

- D = Digital Pin
- I = Input Pin
- O = Output Pin
- OD = Open Drain Pin

## **SPECIFICATIONS**

 $V_{IN}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.

#### Table 2.

Parameter	Symbol	<b>Test Conditions/Comments</b>	Min	Тур	Max	Uni
POWER SUPPLY						
Supply Voltage	VIN		3		25	V
Supply Voltage UVLO Threshold	VIN_UVLO_RISE	Rising edge threshold		3.1	V	V
	VIN_UVLO_FALL	Falling edge threshold		2.9		V
Supply Current	ISC_OPR	V <sub>IN</sub> = 5V, CC is attached, normal		3.3		mA
		operation				
CC1 AND CC2 PINS		•				
Pull-down Voltage in Dead Battery	V <sub>DBL</sub>	194.4µA source current	0.45		1.5	V
	Vdbh	356.5µA source current	0.85		2.45	V
Pull-down resistor	RD		4.6	5.1	5.6	kΩ
Voltage Threshold to Detect a DFP	VTH_DEF	Default current mode	0.15	0.2	0.25	V
	Vth_1p5	1.5A current mode	0.61	0.66	0.70	V
	VTH_3P0	3.0A current mode	1.16	1.23	1.31	V
TX Output Impedance	RTX	PD TX mode	33	48	75	Ω
Voltage Swing				1.125		V
D+/D- PINS						
D- Source Voltage for 0.6V	V <sub>DM_SRC</sub>		0.5	0.6	0.7	V
D+ Source Voltage for 0.6V	V <sub>DP_SRC</sub>		0.5	0.6	0.7	V
Data Detect Voltage	VDAT REF		300	325	350	mν
D- Sink Current			50	100	150	μA
D+ Sink Current			50	100	150	μA
D+/D- Comparator Threshold for	VTH_2P7_HI	High threshold for Apple divider 3	2.85	2.95	3.05	V
2.7V Detection				2.00	0.00	.
	VTH_2P7_LO	Low threshold for Apple divider 3	2.25	2.35	2.45	V
VSET AND ISET PINS						
Source Current		On VSET pin	95	100	105	μA
	liset	On ISET pin	95	100	105	μA
Detect Debounce Time	tdb_vset	For VSET pin		2		ms
	t <sub>DB_ISET</sub>	For ISET pin		2		ms
<sup>2</sup> C PARAMETERS						
Supply Range			2.5		5.5	V
Low Level Input Voltage		Apply for SDA, SCL pins			0.4	V
High Level Input Voltage		Apply for SDA, SCL pins	1.2			V
Low Level Output Voltage		Apply for SDA pin			0.4	V
GATE PIN						
Maximum Sink Current			2		20	mA
Pull Low Impedance				100	300	Ω
PROTECTIONS						
Over-Voltage Protection Threshold	Vvin_ov	Refer to V <sub>IN</sub>	115	120	125	%
OVP Debounce Time	t <sub>DB_OV</sub>			50		μs
Under-Voltage Protection Threshold	Vvin_uv	Refer to V <sub>IN</sub>	-2.2	-2	-1.8	V
UVP Debounce Time	t <sub>DB_UV</sub>			1		ms
Over-Temperature Protection		Rising Threshold		150		°C
Threshold						
		Falling Threshold		130		°C
OTP Debounce Time	t <sub>DB_OT</sub>			100		ms
	R <sub>DIS</sub>			500		Ω

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### **ABSOLUTE MAXIMUM RATINGS**

#### Table 3.

Parameter	Rating
VIN, GATE	-0.3V to +30V
CC1, CC2	-0.3V to +25V
D+, D-	-0.3V to +12V
VSET, ISET, SDA, SCL	-0.3V to +6V
Operating Temperature Range (Junction)	-40°C to +125°C
Soldering Conditions	JEDEC J-STD-020
Electrostatic Discharge (ESD)	
Human Body Mode (HBM)	±6000V

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

#### THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Close attention to PCB thermal design is required.

 $\theta_{JA}$  is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure.

 $\theta_{JC}$  is the junction to case thermal resistance.

#### Table 4. Thermal Resistance

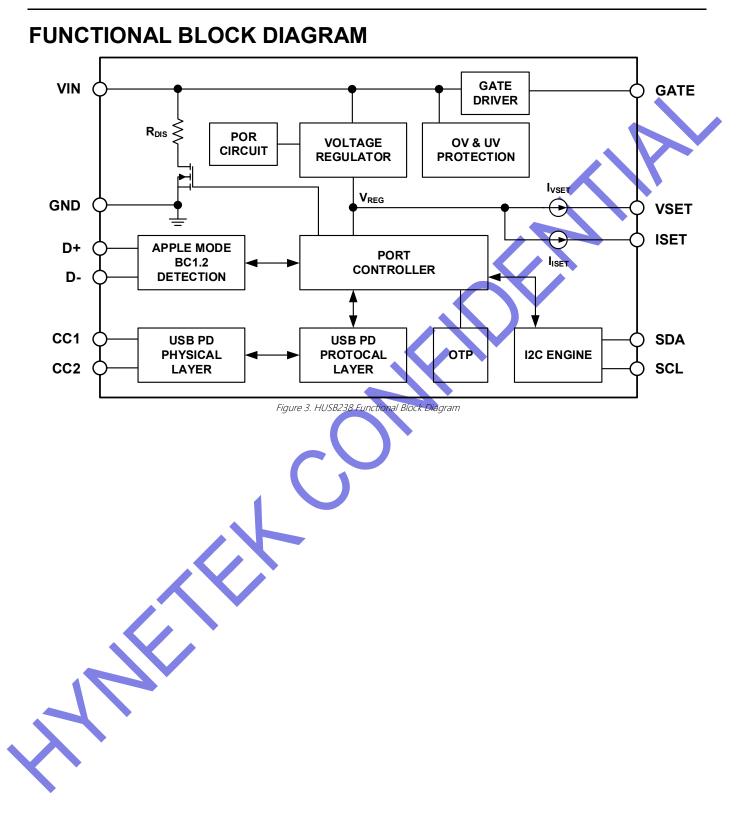
Package Type			θ <sub>JA</sub>	θ」c	Unit
DFN-10L		•	75	54	°C/W

#### ESD CAUTION



#### Electrostatic Discharge Sensitive Device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.



# THEORY OF OPERATION

### OVERVIEW

The HUSB238 is a highly integrated USB Power Delivery (PD) controller as sink role. It's compatible with PD3.0 and Type-C V1.4. It can also support Apple Divider 3, BC1.2 SDP, DCP and CDP while source is attached. When HUSB238 is connected to power source, it applies Rd to both CC lines, trying to establish USB Type-C connection. After the USB Type-C connection is established, it monitors the CC lines to get source capabilities pack from USB PD source. If there is valid source capabilities pack before time out, the HUSB238 policy engine requests a power supply with voltage no greater than the programmed request voltage. If there is no valid source capabilities pack after time out, the HUSB238 switches to Apple divider 3 or BC1.2 mode trying to determine corresponding charging protocol.

#### VIN PIN

VIN pin is the power supply input of the HUSB238, which is derived from the output of the PD source. Connect a 1µF decoupling MLCC between VIN pin and GND pin as closer as possible.

The VIN pin is also connected to an internal MOSFET and 5000hm discharging resistor, which is used as a bleeder to help discharge the output capacitor to vSafe5V upon the hard reset, over-voltage fault, over-temperature fault or detachment of a connected device.

#### **GATE PIN**

The GATE pin is open-drain output which allows to drive an external PMOS load switch directly. The GATE pin can be programmed to turn on after POR or after the explicit contract. The default option is to turn on after POR. Please contact local Hynetek sales for a device with options other than the default option.

#### CC1 AND CC2 PINS

CC1 and CC2 are the Configuration Channel pins used for connection and attachment detection, plug orientation determination and system configuration management across USB Type-C cable. CC1 and CC2 pins can support as high as 25V voltage, which is used for protection when CC1 or CC2 is shorted to VBUS pin on the connector.

Through the Type-C detection, one of the CC pin is connected to the internal BMC block to achieve PD communication.

#### VSET PIN

A fixed 100µA current source is applied on VSET pin. Connect a resister between VSET and GND to indicate the VSET\_VOLTAGE value as shown in Table 5.

etting
VSET_VOLTAGE (V)
5
9
12
15
18
20

Table 5. VSET\_VOLTAGE Setting

The RDO voltage of the HUSB238 is determined by the lower value between VSET\_VOLTAGE and SNK\_PDO2\_VOLTAGE. SNK\_PDO2\_VOLTAGE is programmable by internal fuse options and the default value is 20V. The requested voltage value can be changed dynamically with the resistance value change.

### **ISET PIN**

A fixed 100μA current source is applied on ISET pin. Connect a resister between ISET and GND to indicate the ISET\_CURRENT value as shown in Table 6.

Table	6. ISET	CURRENT	Settina
Ianio			eetting

R <sub>ISET</sub> (kΩ)	ISET_CURERNT (A)
0	1.25
4.53	1.5

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R <sub>ISET</sub> (kΩ)	ISET_CURERNT (A)	
7.5	1.75	
10.5	2	
13.7	2.25	
16.5	2.5	
19.6	2.75	
22.6	3	
Open	3.25	

The RDO current of the HUSB238 is determined by the lower value between ISET\_CURRENT and SNK\_PDO2\_CURRENT. SNK\_PDO2\_CURRENT is programmable by internal fuse options and the default value is 3.25A. The requested current value can be changed dynamically with the resistance value change.

#### **RDO DETERMINATION**

There are two ways to determine the RDO that the HUSB238 requests from the PD source. Set by the VSET and ISET pins or set by the internal factory programmed fuse options. The HUSB238 compares the two values and uses the lower value as its RDO.

For example, if the VSET and ISET is configured as 9V / 3A. The internal factory fuse option is 12V / 2A. Then the RDO that HUSB238 requests from the PD source is 9V / 2A.

After the RDO is determined, the HUSB238 loops through the PD source PDOs from highest voltage first to find the first PDO that satisfies the following conditions:

- 1. SOURCE\_PDO\_VOLTAGE ≤ RDO\_VOLTAGE
- 2. SOURCE PDO CURRENT ≥ RDO CURRENT

If both the conditions above are satisfied, then HUSB238 sends a request for this source PDO with operating current set to the RDO current value.

If either one of the condition is not satisfied, the HUSB238 continues to compare with the second highest voltage source PDO or requests 5V source PDO directly, depending on the internal fuse options. The default fuse option is to continue to compare with the second highest voltage source PDO. Please contact local Hynetek sales for a device with options other than the default option.

### **OPERATION WITH I<sup>2</sup>C INTERFACE**

The HUSB238 is I<sup>2</sup>C communication capable with system MCU or processor through SDA and SCL pins. The HUSB238 works as I<sup>2</sup>C slave role and the I<sup>2</sup>C address is 0x08.

After POR (Power On Reset), the HUSB238 receives the source capability information from the PD source adapter and the HUSB238 saves the source capability information in registers. The system MCU can visit the HUSB238 registers through the I<sup>2</sup>C bus and select a proper PDO to request from external PD source.

The I<sup>2</sup>C has the highest priority. If using I<sup>2</sup>C to select a source PDO, it over writes the internal RDO which is created by VSET, ISET pins and internal factory fuse option, and the HUSB238 requests the I<sup>2</sup>C selected source PDO once the I2C commands are written.

### LEGACY CHARGER DETECTION

After the power on reset, if the HUSB238 does not establish PD contract with source adapter, the HUSB238 will waits for 1.5 seconds and then switches to Apple Divider 3 and BC1.2 detections sequentially. For BC1.2 detection, the HUSB238 detects SDP (Standard Data Port), CDP (Charging Data Port) and DCP (Dedicated Charging Port) sequentially.

### **DEAD BATTERY FUNCTION**

The HUSB238 works as PD sink role which requires R<sub>D</sub> resistor to be presented on the CC pins even in the unpowered state for successful Type-C detection by source adapter.

The dead battery function in the HUSB238 supports default USB, 1.5A and 3.0A source broadcast RP current.

#### **SOP' FUNCTION**

For the USB-C to legacy PC plug applications where high current and high voltage are required, the system needs current more than 3A in most of the cases. If the SOP' function is enabled, the HUSB238 is capable to reply SOP' command, such as Discover Identity, sent by the PD source adapter.

The SOP' function emulates the E-Marker function in the cable so that the system is capable of obtaining more than 3A charging current from PD source adapter.

#### **OVER-VOLTAGE PROTECTION**

The HUSB238 senses the voltage on VIN pin for overvoltage protection. The over-voltage threshold is 1.2 times of max requested voltage. The OV debounce time is  $50\mu$ s.

When OV happens, the HUSB238 turns off the external PMOS and enters into discharge mode where the internal discharge circuit on VIN pin is turned on. The internal 5.1k Rd resistor is also disconnected during discharge mode. After the discharge timeout, the HUSB238 enters into unattached mode and waits for re-connection with PD source adapter.

#### **UNDER-VOLTAGE PROTECTION**

The HUSB238 senses the voltage on VIN pin for optional under-voltage protection. The under-voltage threshold is the requested voltage minus 2V. For example, if the requested PDO voltage is 12V, then the UV threshold is 10V. The UV debounce time is 1ms.

When UV happens, the HUSB238 turns off the external PMOS and enters into discharge mode where the internal discharge circuit on VIN pin is turned on. The internal 5.1k Rd resistor is also disconnected during discharge mode. After the discharge timeout, the HUSB238 enters into unattached mode and waits for re-connection with PD source adapter.

The UVP function of the HUSB238 can be enabled or disabled by internal fuse options. The UVP function is disabled for default option. Please contact local Hynetek sales for a device with options other than the default option.

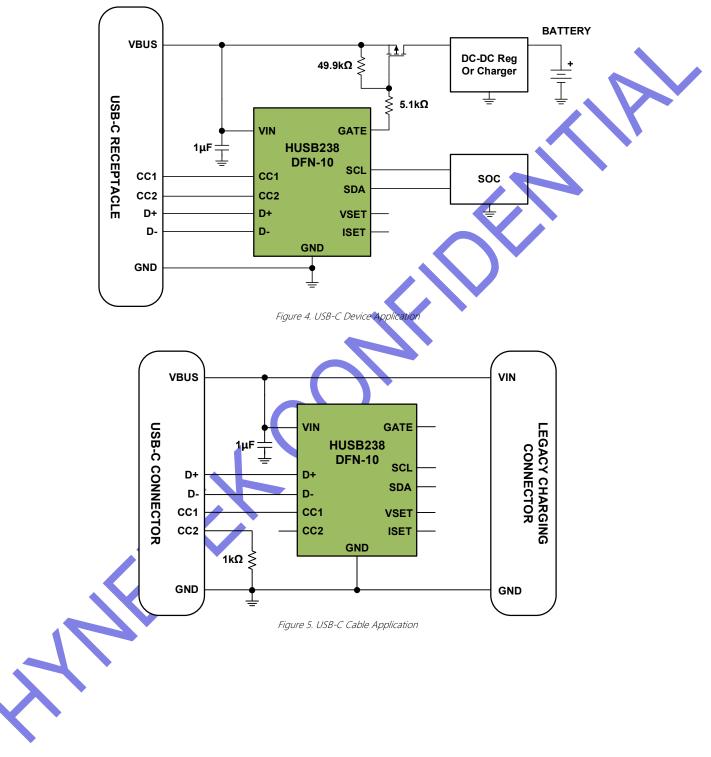
### **OVER-TEMPERATURE PROTECTION**

The HUSB238 integrates over-temperature protection function. It monitors the internal junction temperature. When the junction temperature reaches the over temperature rising threshold, the HUSB238 requests 5V source PDO directly, regardless of the previous established PDO, to reduce the total system power. When the junction temperature falls below the over temperature falling threshold, the HUSB238 re-negotiates the previous PDO and tries to recover the normal charging operation.

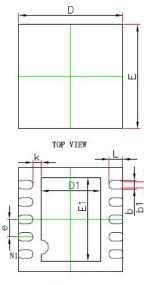
The over temperature thresholds are programmable by internal factory fuses. Please contact local Hynetek sales for a device with options other than the default option.

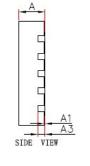






# PACKAGE OUTLINE DIMENSIONS







	Dimension	on In Millimeters	
Symbo	Min	Max	
A	0.700	0.800	
A1	0.000	0.050	
A3	0.20	)3REF	
D	2.900	3.100	
E	2.900	3.100	
D1	1.600	1.800	
E1	2.300	2.500	
k	0.250	0.275	
b	0.200	0.300	
b1	0.180	0.230	
e	0.50	OBSC	
L	0.324	0.476	

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# **ORDERING GUIDE**

Model	Package	SOP'	OTP Threshold	<b>RDO Mismatch Action</b>	Package Option
HUSB238_001DD	DFN-10L	YES	90°C / 75°C	Request 5V	Tape & Reel, 4k
HUSB238_002DD	DFN-10L	NO	150°C / 130°C	Next PDO	Tape & Reel, 4k
HUSB238_003DD	DFN-10L	YES	90°C / 75°C	Next PDO	Tape & Reel, 4k
HUSB238_004DD	DFN-10L	NO	150°C / 130°C	Request 5V	Tape & Reel, 4k

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